

Automotive Dual N-Channel 30 V (D-S) 175 °C MOSFET

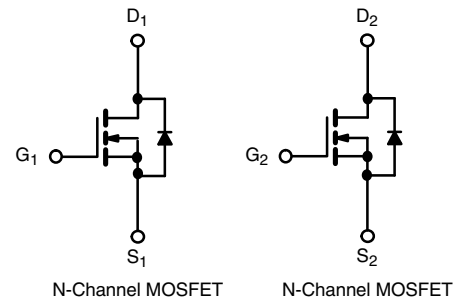
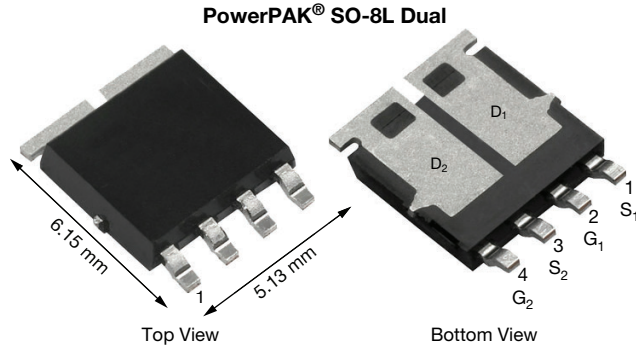
| PRODUCT SUMMARY | |
|---|----------------|
| V_{DS} (V) | 30 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = 10$ V | 0.0166 |
| $R_{DS(on)}$ (Ω) at $V_{GS} = 4.5$ V | 0.0276 |
| I_D (A) per leg | 8 |
| Configuration | Dual |
| Package | PowerPAK SO-8L |

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization:
for definitions of compliance please
see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE



| ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted) | | | | |
|---|----------------|----------------|-------------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Drain-Source Voltage | | V_{DS} | 30 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | |
| Continuous Drain Current ^a | $T_C = 25$ °C | I_D | 8 | A |
| | $T_C = 125$ °C | | 8 | |
| Continuous Source Current (Diode Conduction) ^a | | I_S | 8 | |
| Pulsed Drain Current ^b | | I_{DM} | 32 | |
| Single Pulse Avalanche Current | | I_{AS} | 23 | |
| Single Pulse Avalanche Energy | | E_{AS} | 26 | mJ |
| Maximum Power Dissipation ^b | $T_C = 25$ °C | P_D | 48 | W |
| | $T_C = 125$ °C | | 16 | |
| Operating Junction and Storage Temperature Range | | T_J, T_{stg} | -55 to +175 | °C |
| Soldering Recommendations (Peak Temperature) ^{d, e} | | | 260 | |

| THERMAL RESISTANCE RATINGS | | | | |
|----------------------------|------------------------|------------|-------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Junction-to-Ambient | PCB Mount ^c | R_{thJA} | 85 | °C/W |
| Junction-to-Case (Drain) | | R_{thJC} | 3.1 | |

Notes

- Package limited.
- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR4 material).
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



| SPECIFICATIONS (T _C = 25 °C, unless otherwise noted) | | | | | | | |
|---|---------------------|--|---|------|--------|--------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | V _{GS} = 0, I _D = 250 μA | | 30 | - | - | V |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D = 250 μA | | 1.5 | 2.0 | 2.5 | |
| Gate-Source Leakage | I _{GSS} | V _{DS} = 0 V, V _{GS} = ± 20 V | | - | - | ± 100 | nA |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{GS} = 0 V | V _{DS} = 30 V | - | - | 1 | μA |
| | | V _{GS} = 0 V | V _{DS} = 30 V, T _J = 125 °C | - | - | 50 | |
| | | V _{GS} = 0 V | V _{DS} = 30 V, T _J = 175 °C | - | - | 150 | |
| On-State Drain Current ^a | I _{D(on)} | V _{GS} = 10 V | V _{DS} ≥ 5 V | 30 | - | - | A |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = 10 V | I _D = 7.6 A | - | 0.0138 | 0.0166 | Ω |
| | | V _{GS} = 4.5 V | I _D = 5.9 A | - | 0.0230 | 0.0276 | |
| | | V _{GS} = 10 V | I _D = 7.6 A, T _J = 125 °C | - | - | 0.0252 | |
| | | V _{GS} = 10 V | I _D = 7.6 A, T _J = 175 °C | - | - | 0.0300 | |
| Forward Transconductance ^b | g _{fs} | V _{DS} = 15 V, I _D = 7.6 A | | - | 20 | - | S |
| Dynamic ^b | | | | | | | |
| Input Capacitance | C _{iss} | V _{GS} = 0 V | V _{DS} = 15 V, f = 1 MHz | - | 929 | 1161 | pF |
| Output Capacitance | C _{oss} | | | - | 280 | 350 | |
| Reverse Transfer Capacitance | C _{rss} | | | - | 93 | 116 | |
| Total Gate Charge ^c | Q _g | V _{GS} = 10 V | V _{DS} = 15 V, I _D = 10 A | - | 17 | 26 | nC |
| Gate-Source Charge ^c | Q _{gs} | | | - | 3 | - | |
| Gate-Drain Charge ^c | Q _{gd} | | | - | 3 | - | |
| Gate Resistance | R _g | f = 1 MHz | | 1.1 | - | 5 | Ω |
| Turn-On Delay Time ^c | t _{d(on)} | V _{DD} = 15 V, R _L = 15 Ω I _D ≡ 1 A, V _{GEN} = 10 V, R _g = 6 Ω | | - | 4.5 | 7 | ns |
| Rise Time ^c | t _r | | | - | 10 | 15 | |
| Turn-Off Delay Time ^c | t _{d(off)} | | | - | 20 | 30 | |
| Fall Time ^c | t _f | | | - | 7 | 10 | |
| Source-Drain Diode Ratings and Characteristics ^b | | | | | | | |
| Pulsed Current ^a | I _{SM} | | | - | - | 32 | A |
| Forward Voltage | V _{SD} | I _F = 4.3 A, V _{GS} = 0 | | - | 0.8 | 1.2 | V |

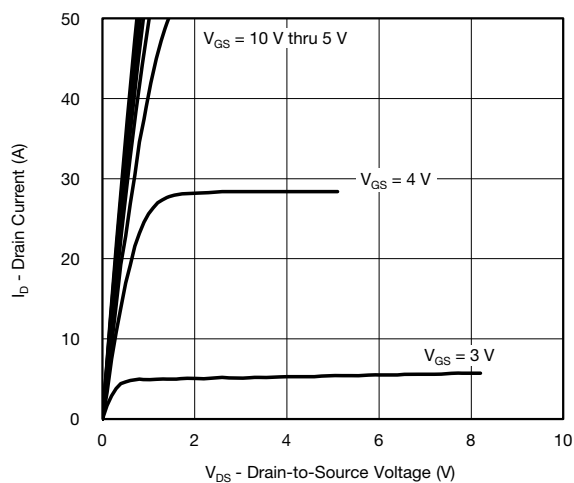
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

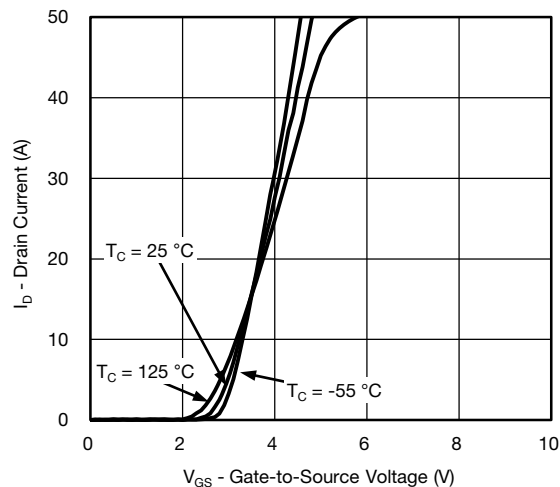
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



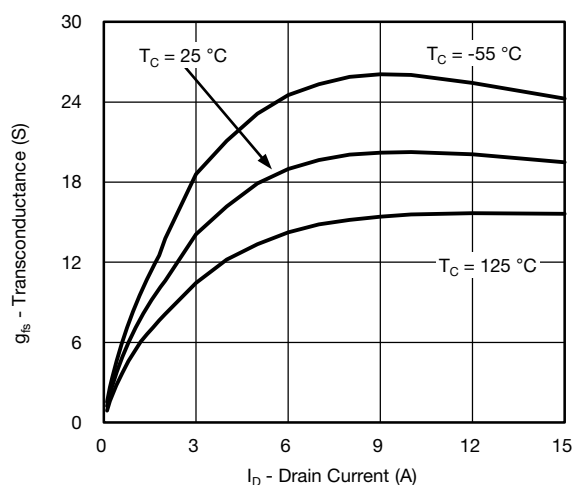
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



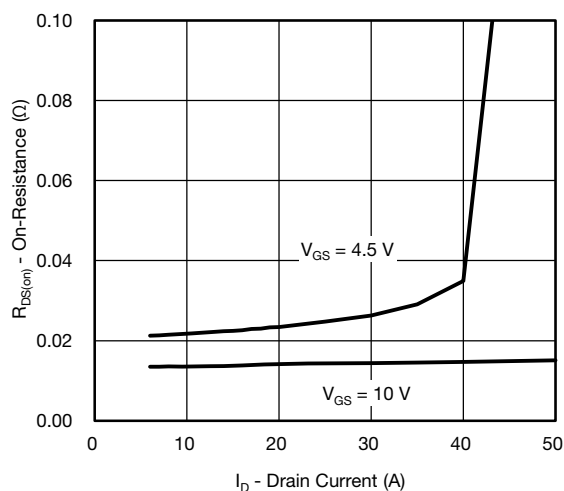
Output Characteristics



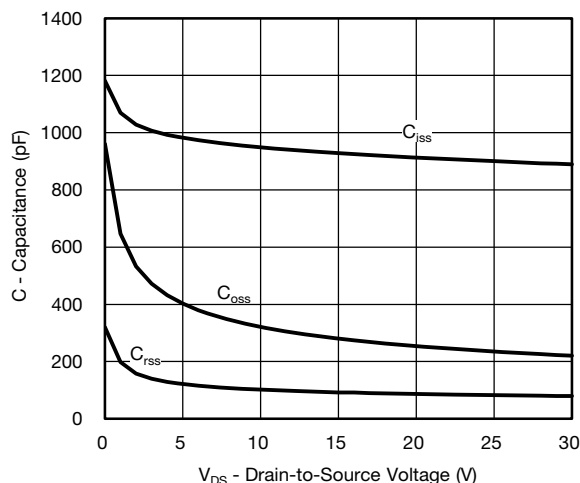
Transfer Characteristics



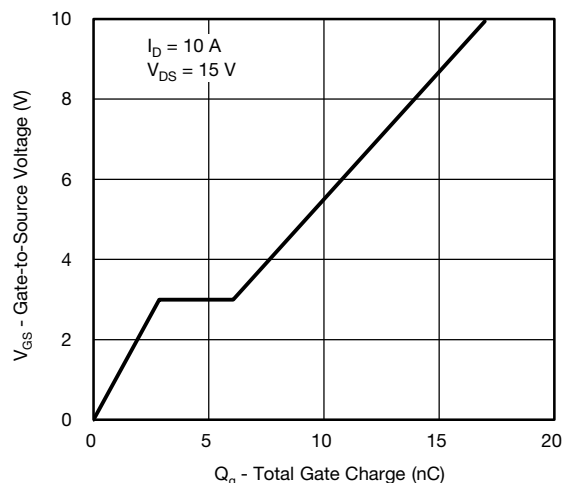
Transconductance



On-Resistance vs. Drain Current



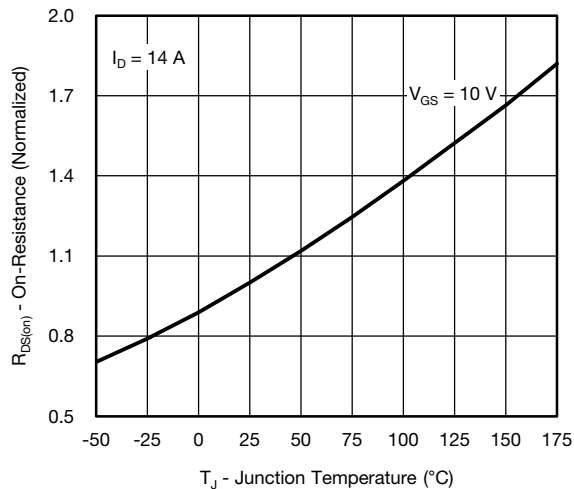
Capacitance



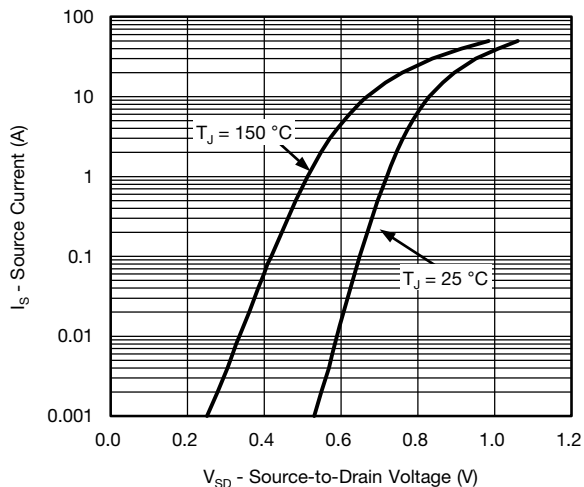
Gate Charge



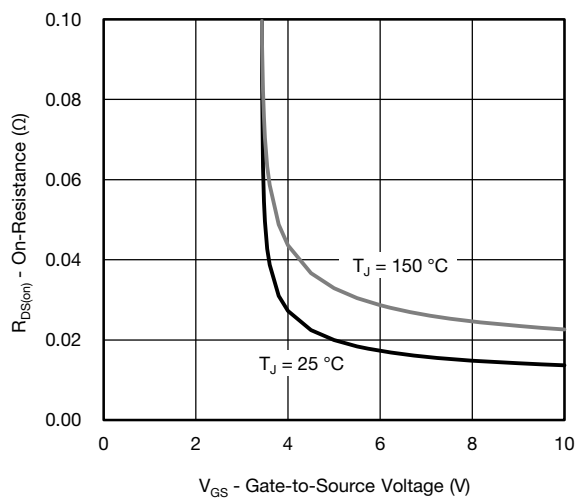
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



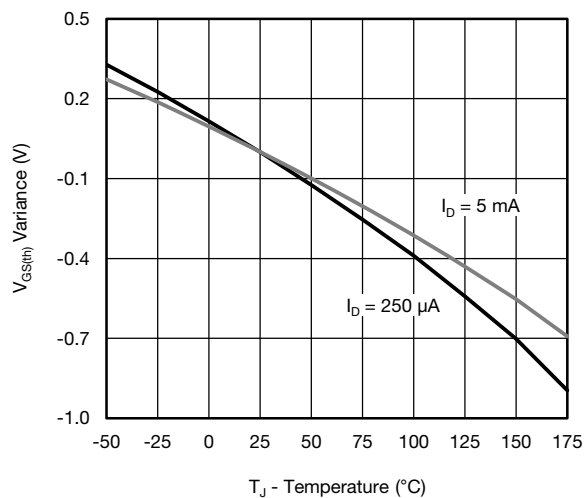
On-Resistance vs. Junction Temperature



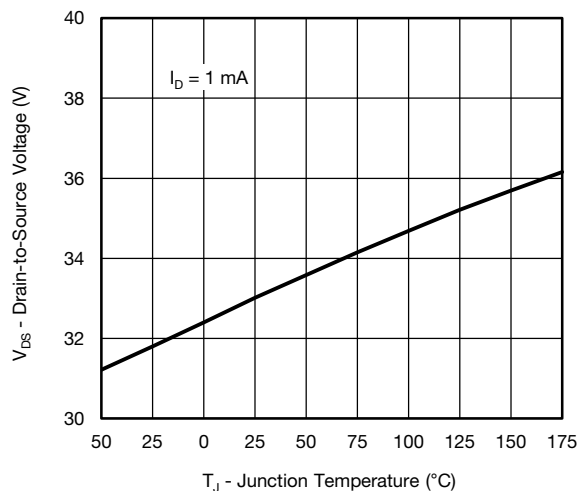
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



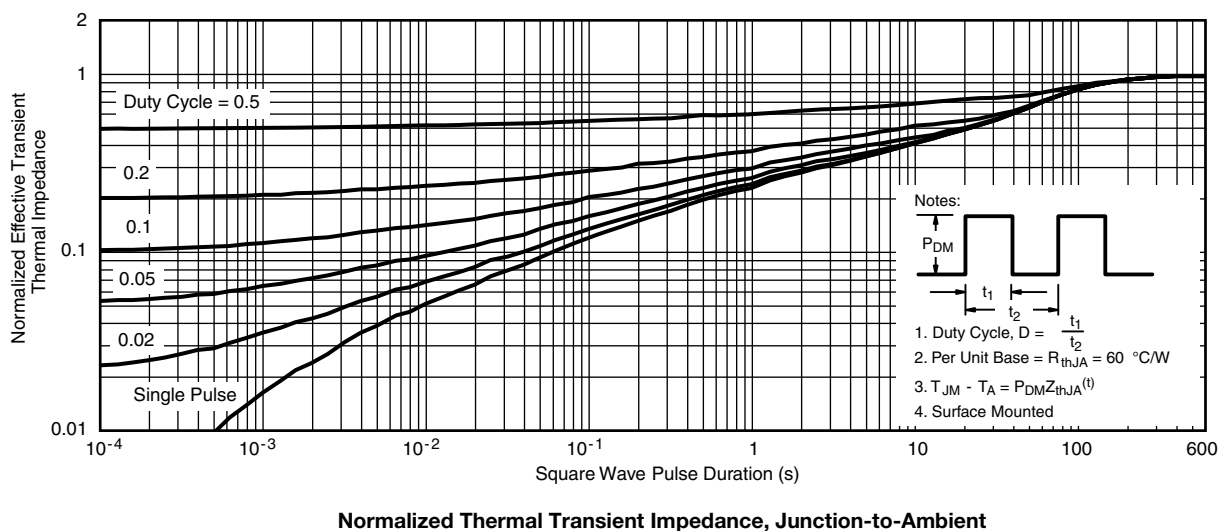
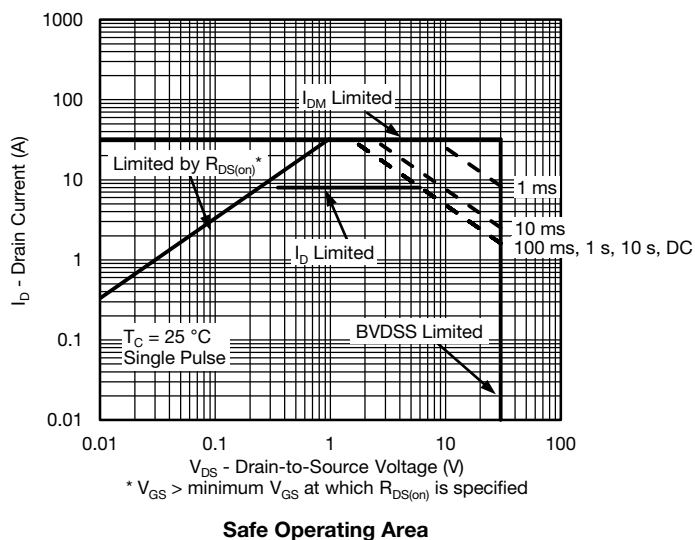
Threshold Voltage



Drain Source Breakdown vs. Junction Temperature

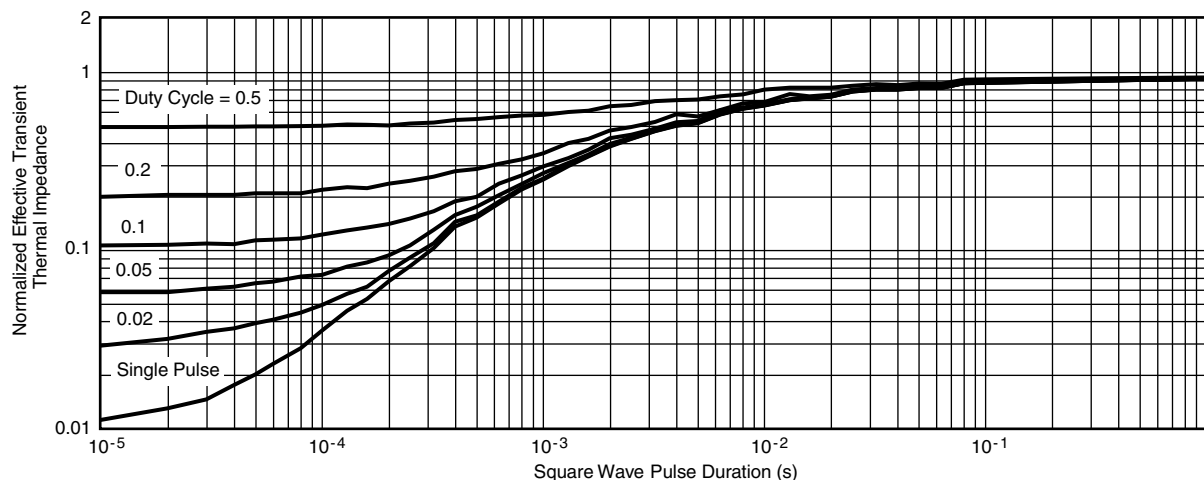


THERMAL RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)





THERMAL RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^{\circ}\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Case ($25\text{ }^{\circ}\text{C}$)are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62832.



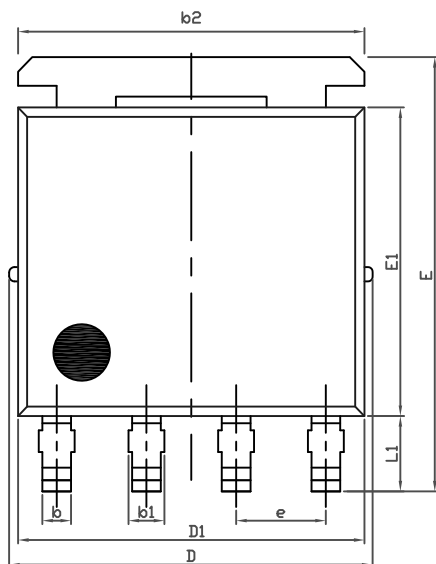
| REVISION HISTORY ^a | | |
|-------------------------------|-----------|--|
| REVISION | DATE | DESCRIPTION OF CHANGE |
| B | 04-Aug-15 | • Revised R _g minimum limit |

Note

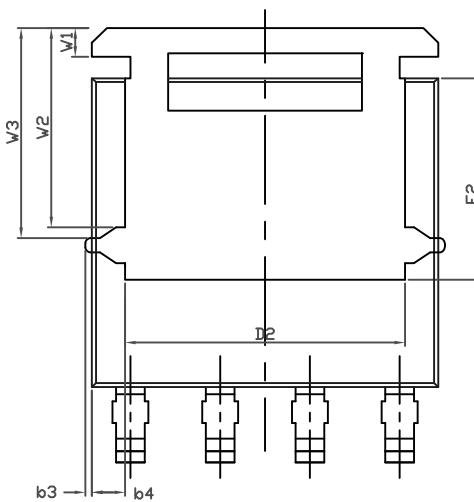
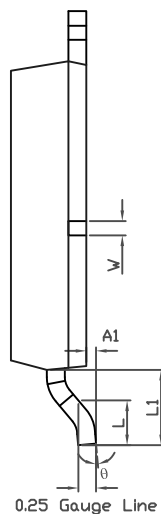
a. As of April 2014



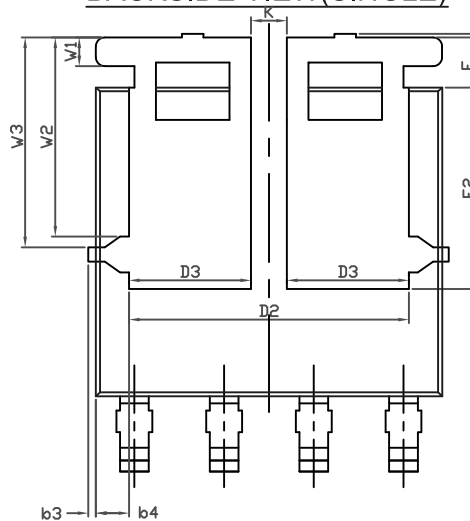
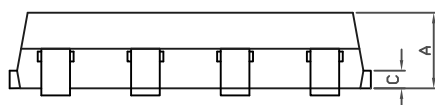
PowerPAK® SO-8L Case Outline for Al Parts



TOPSIDE VIEW



BACKSIDE VIEW(SINGLE)



BACKSIDE VIEW(DUAL)



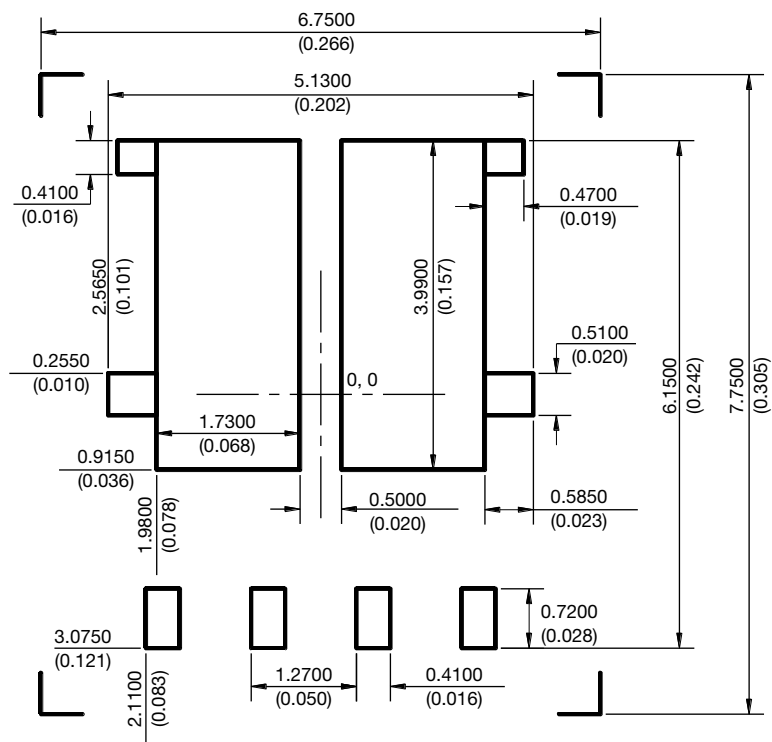
| DIM. | MILLIMETERS | | | INCHES | | |
|--|-------------|------|-------|-----------|-------|-------|
| | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A | 1.00 | 1.07 | 1.14 | 0.039 | 0.042 | 0.045 |
| A1 | 0.00 | - | 0.127 | 0.00 | - | 0.005 |
| b | 0.33 | 0.41 | 0.48 | 0.013 | 0.016 | 0.019 |
| b1 | 0.44 | 0.51 | 0.58 | 0.017 | 0.020 | 0.023 |
| b2 | 4.80 | 4.90 | 5.00 | 0.189 | 0.193 | 0.197 |
| b3 | 0.094 | | | 0.004 | | |
| b4 | 0.47 | | | 0.019 | | |
| c | 0.20 | 0.25 | 0.30 | 0.008 | 0.010 | 0.012 |
| D | 5.00 | 5.13 | 5.25 | 0.197 | 0.202 | 0.207 |
| D1 | 4.80 | 4.90 | 5.00 | 0.189 | 0.193 | 0.197 |
| D2 | 3.86 | 3.96 | 4.06 | 0.152 | 0.156 | 0.160 |
| D3 | 1.63 | 1.73 | 1.83 | 0.064 | 0.068 | 0.072 |
| e | 1.27 BSC | | | 0.050 BSC | | |
| E | 6.05 | 6.15 | 6.25 | 0.238 | 0.242 | 0.246 |
| E1 | 4.27 | 4.37 | 4.47 | 0.168 | 0.172 | 0.176 |
| E2 | 2.75 | 2.85 | 2.95 | 0.108 | 0.112 | 0.116 |
| F | - | - | 0.15 | - | - | 0.006 |
| L | 0.62 | 0.72 | 0.82 | 0.024 | 0.028 | 0.032 |
| L1 | 0.92 | 1.07 | 1.22 | 0.036 | 0.042 | 0.048 |
| K | 0.51 | | | 0.020 | | |
| W | 0.23 | | | 0.009 | | |
| W1 | 0.41 | | | 0.016 | | |
| W2 | 2.82 | | | 0.111 | | |
| W3 | 2.96 | | | 0.117 | | |
| q | 0° | - | 10° | 0° | - | 10° |
| ECN: C15-1203-Rev. A, 07-Sep-15 DWG: 6044 | | | | | | |

Note

- Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL



Recommended Minimum Pads
Dimensions in mm (inches)
Keep-out 6.75 (0.266) x 7.75 (0.305)



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